

# Journal of Semiconductors

Volume 30 Number 5 May 2009

## SEMICONDUCTOR PHYSICS

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Zhuo Shiyi, Xiong Yuying, and Gu Min

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Chen Huimin, Guo Fuqiang, and Zhang Baohua
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Zhang Jian, Li Tingju, Ma Xiaodong, Luo Dawei, Liu Ning, and Liu Dehua

## SEMICONDUCTOR DEVICES

- 054001** Annealing before gate metal deposition related noise performance in AlGaIn/GaN HEMTs (4 pages)  
Pang Lei, Pu Yan, Liu Xinyu, Wang Liang, Li Chengzhan, Liu Jian, Zheng Yingkui, and Wei Ke
- 054002** Development and characteristics analysis of recessed-gate MOS HEMT (4 pages)  
Wang Chong, Ma Xiaohua, Feng Qian, Hao Yue, Zhang Jincheng, and Mao Wei
- 054003** A novel MEMS inertial sensor with enhanced sensing capacitors (7 pages)  
Dong Linxi, Yan Haixia, Huo Weihong, Xu Li, Li Yongjie, and Sun Lingling
- 054004** A capacitive membrane MEMS microwave power sensor in the X-band based on GaAs MMIC technology (4 pages)  
Su Shi and Liao Xiaoping
- 054005** Epitaxy and Characteristics of Resonant Cavity LEDs at 650 nm (3 pages)  
Kang Yuzhu, Li Jianjun, Ding Liang, Yang Zhen, Han Jun, Deng Jun, Zou Deshu, and Shen Guangdi
- 054006** A novel symmetrical microwave power sensor based on MEMS technology (5 pages)  
Wang Debo and Liao Xiaoping
- 054007** Numerical analysis of four-wave-mixing based multichannel wavelength conversion techniques in fibers (5 pages)  
Jia Liang, Zhang Fan, Li Ming, Liu Yuliang, and Chen Zhangyuan

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Zheng Yuzhan, Lu Wu, Ren Diyuan, Wang Yiyuan, Guo Qi, and Yu Xuefeng

(Continued on inside back cover)

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Wu Tuo, Chen Hongyi, and Qian Dahong
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Yin Jiangwei, Li Ning, Zheng Renliang, Li Wei, and Ren Junyan
- 055004 A 540- $\mu$ W digital pre-amplifier with 88-dB dynamic range for electret microphones (5 pages)**  
Liu Yan, Hua Siliang, Wang Donghui, and Hou Chaohuan
- 055005 Design of a 40-GHz LNA in 0.13- $\mu$ m SiGe BiCMOS (4 pages)**  
Xu Leijun, Wang Zhigong, Li Qin, and Zhao Yan
- 055006 Modeling and analysis of single-event transients in charge pumps (5 pages)**  
Zhao Zhenyu, Li Junfeng, Zhang Minxuan, and Li Shaoqing
- 055007 A 20-Gb/s 1 : 2 demultiplexer in 0.18- $\mu$ m CMOS (5 pages)**  
Zhang Changchun, Wang Zhigong, Shi Si, and Li Wei
- 055008 A 2.4-GHz SiGe HBT power amplifier with bias current controlling circuit (3 pages)**  
Peng Yanjun, Song Jiayou, Wang Zhigong, and Tsang K F
- 055009 Design of Ka-band antipodal finline mixer and detector (4 pages)**  
Yao Changfei, Xu Jinping, and Chen Mo
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Li Liang, Li Ruzhang, Yu Zhou, Zhang Jiabin, and Zhang Jun'an
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Zhu Xubin, Ni Weining, and Shi Yin
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Yu Changliang, Mao Luhong, Xiao Xindong, Xie Sheng, and Zhang Shilin

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Zhao Wenbin, Chen Haifeng, Xiao Zhiqiang, Li Leilei, and Yu Zongguang